

BTB20

Rev.E Mar.-2016

描述 / Descriptions

TO-220 塑封封装双向可控硅。 Triac in a TO-220 Plastic Package.

特征 / Features

中电流可控硅，低通态压降，高可靠性和稳定性，低热敏电阻特性，高转换性能。

Medium current triac, Low on state voltage drop, High reliability and stability, Low thermal resistance, High commutation performances.

用途 / Applications

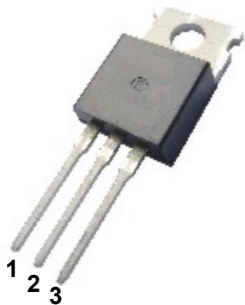
用于电源交流开关转换，如感应或电阻负载的相位控制和静态切换电路等。

For power AC switching operations. Such as phase control and static switching on inductive or resistive load, etc.

内部等效电路 / Equivalent Circuit



引脚排列 / Pinning



PIN1 : Main Terminal 1 PIN 2 : Main Terminal 2 PIN 3: Gate

放大及印章代码 / h_{FE} Classifications & Marking

见印章说明。 See Marking Instructions.

极限参数 / Absolute Maximum Ratings(Ta=25°C)

参数 Parameter	符号 Symbol	数值 Rating	单位 Unit
Repetitive peak off-state voltages	V_{DRM}/V_{RRM}	600/700	V
On-state rms current(full sine wave $T_C=70^\circ\text{C}$)	$I_{T(RMS)}$	20	A
Non repetitive surge peak on-state current(full cycle, T_j initial = 25 °C)	$I_{TSM}(F=50\text{Hz}$ $t=10\text{ms})$	210	A
Non repetitive surge peak on-state current(full cycle, T_j initial = 25 °C)	$I_{TSM}(F=60\text{Hz}$ $t=8.3\text{ms})$	200	A
I_t^2 value for fusing	$I_t^2(t_p=10\text{ms})$	200	A^2s
Critical rate of rise of on-state current $I_G=2I_{GT}$, $t_r \leq 100$ ns ($F=50\text{Hz}$ $T_j=125^\circ\text{C}$)	dI/dt	50	$\text{A}/\mu\text{s}$
Critical rate of rise of on-state current $I_G=2I_{GT}$, $t_r \leq 100$ ns ($T_j=125^\circ\text{C}$)		100	
Non repetitive peak off-state Voltage($t_p=10$ ms $T_j=25^\circ\text{C}$)	V_{DSM}/V_{RSM}	V_{DRM}/V_{RRM} + 100	V
Peak gate current($t_p=20\mu\text{s}$ $T_j=125^\circ\text{C}$)	I_{GM}	4.0	A
Peak positive gate voltage($t_p=20\mu\text{s}$)	V_{GM}	16	V
Average gate power dissipation($T_j=125^\circ\text{C}$)	$P_{G(AV)}$	1.0	W
Operating junction temperature range	T_j	-40~125	$^\circ\text{C}$
Storage junction temperature range	T_{stg}	-40~150	$^\circ\text{C}$
Junction to ambient	$R_{th(j-a)}$	60	$^\circ\text{C}/\text{W}$
Junction to case for AC	$R_{th(j-c)}$	2.1	
Junction to case for DC	$R_{th(j-c)}$	2.8	

电性能参数 / Electrical Characteristics(Ta=25°C)

符号 Symbol	测试条件 Test Conditions	信号区 Quadrant	BTB20		单位 Unit	
			BW	CW		
$I_{GT}^{(1)}$	$V_D=12\text{V}$ $R_L=33\Omega$	ALL	Min.	2.0	1.0	mA
			Max.	50	35	
V_{GT}		ALL	Max.	1.5		V
V_{GD}	$V_D=V_{DRM}$ $R_L=3.3\text{K}\Omega$ $T_j=125^\circ\text{C}$	ALL	Min.	0.2		V
$I_H^{(2)}$	$I_T=500\text{mA}$, gate open		Max.	75	50	mA
I_L	$I_G=1.2I_{GT}$	I-III	Typ.	50	-	mA
		II		90	-	
		I- II -III	Max.	-	80	
dV/dt ⁽²⁾	$V_D=67\%$ V_{DRM} , gate open $T_j=125^\circ\text{C}$		Typ.	750	500	$\text{V}/\mu\text{s}$
			Min.	500	250	
(dV /dt)c ⁽²⁾	(dI/dt)c = 20A/ms $T_j=125^\circ\text{C}$		Typ.	36	22	$\text{V}/\mu\text{s}$
			Min.	18	11	

Note 1: minimum I_{GT} is guaranteed at 5% of I_{GT} max.

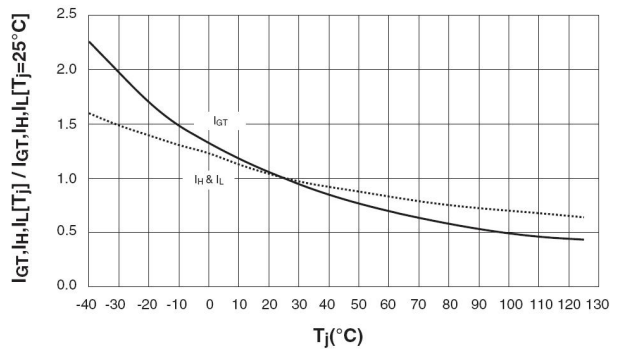
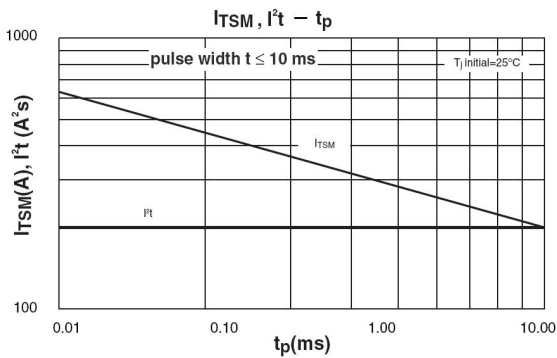
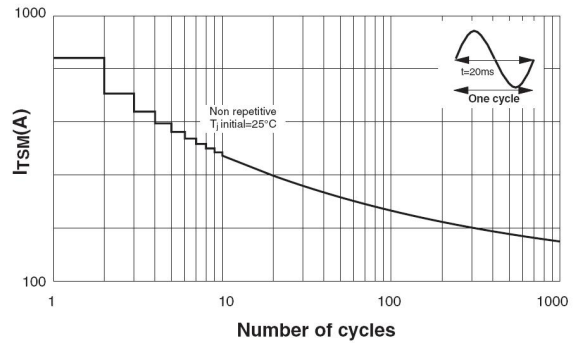
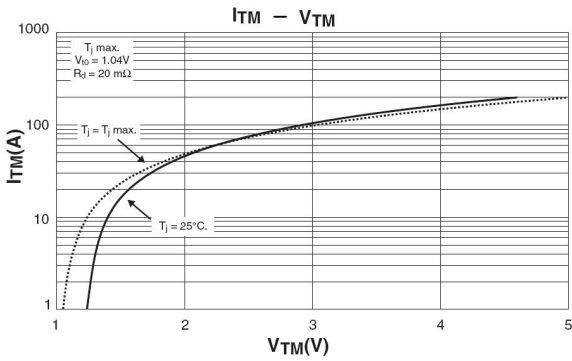
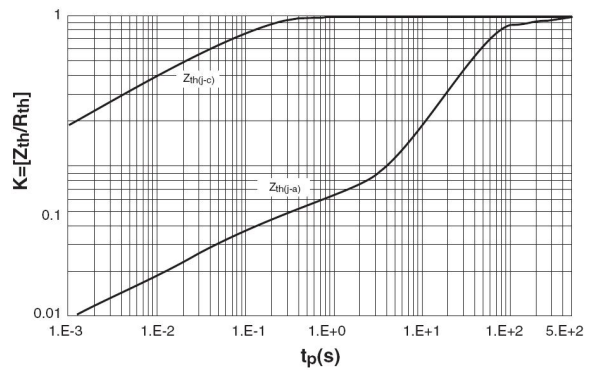
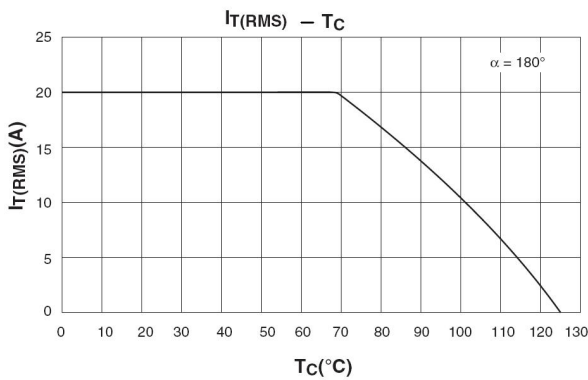
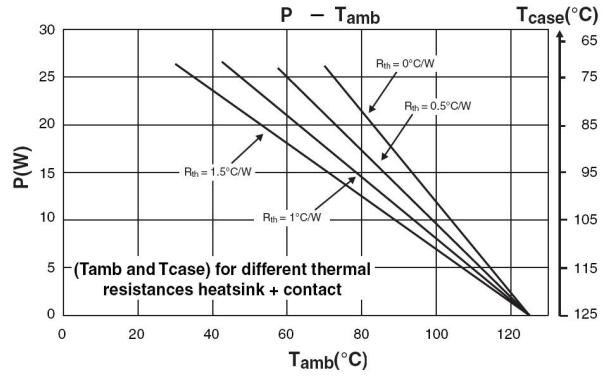
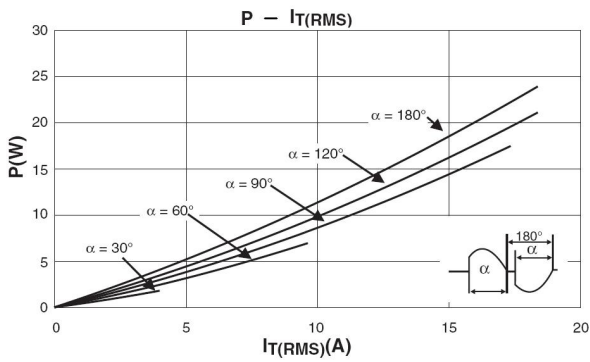
Note 2: for both polarities of A2 referenced to A1.

电性能参数 / Electrical Characteristics(Ta=25°C)

符号 Symbol	测试条件 Test Conditions			数值 Value	单位 Unit
$V_{TM}^{(1)}$	$I_{TM}=28A$	$t_p = 380\mu s$	$T_j=125^\circ C$	Max.	1.7 V
I_{DRM} I_{RRM}	$V_{DRM} = V_{RRM}$		$T_j=25^\circ C$	Max.	10 μA
			$T_j=125^\circ C$	Max.	3.0 mA

Note1. for both polarities of A2 referenced to A1

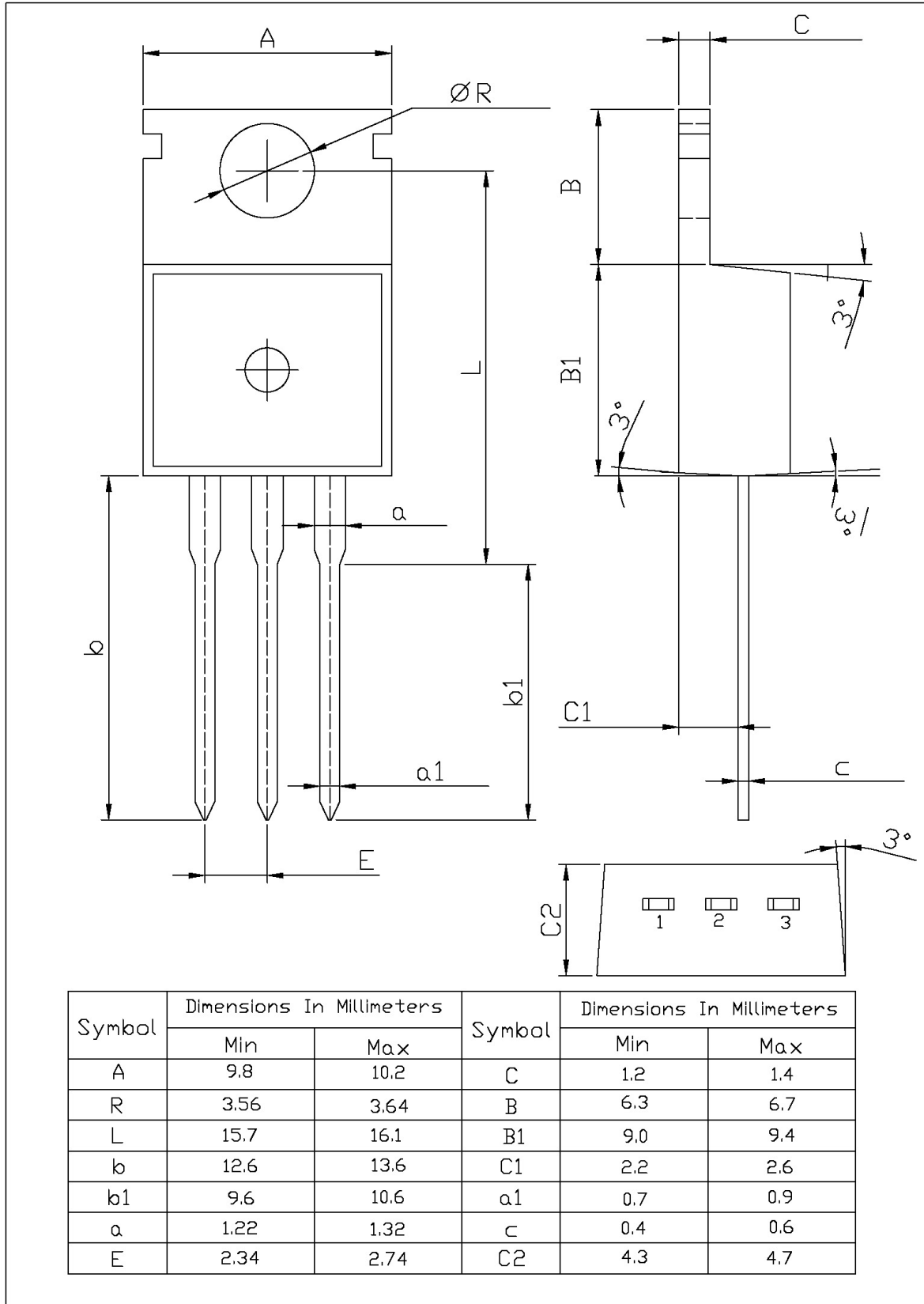
电参数曲线图 / Electrical Characteristic Curve



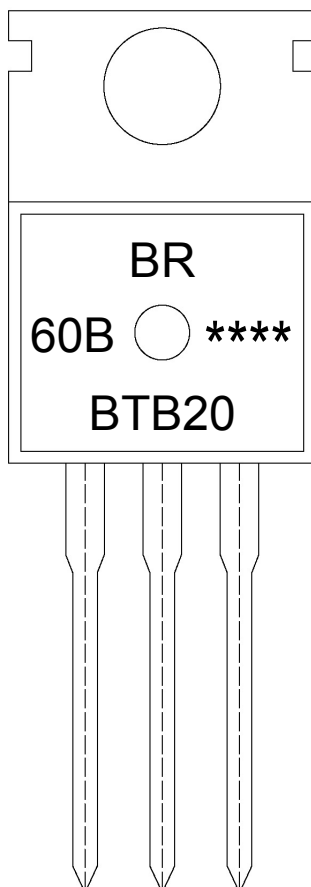
外形尺寸图 / Package Dimensions

T0-220

单位: mm



印章说明 / Marking Instructions



说明：

BR： 为公司代码

BTB20： 为产品型号

60B： 为 V_{RRM} 和 I_{GT} 分档代码

****： 为生产批号代码，随生产批号变化。

Note:

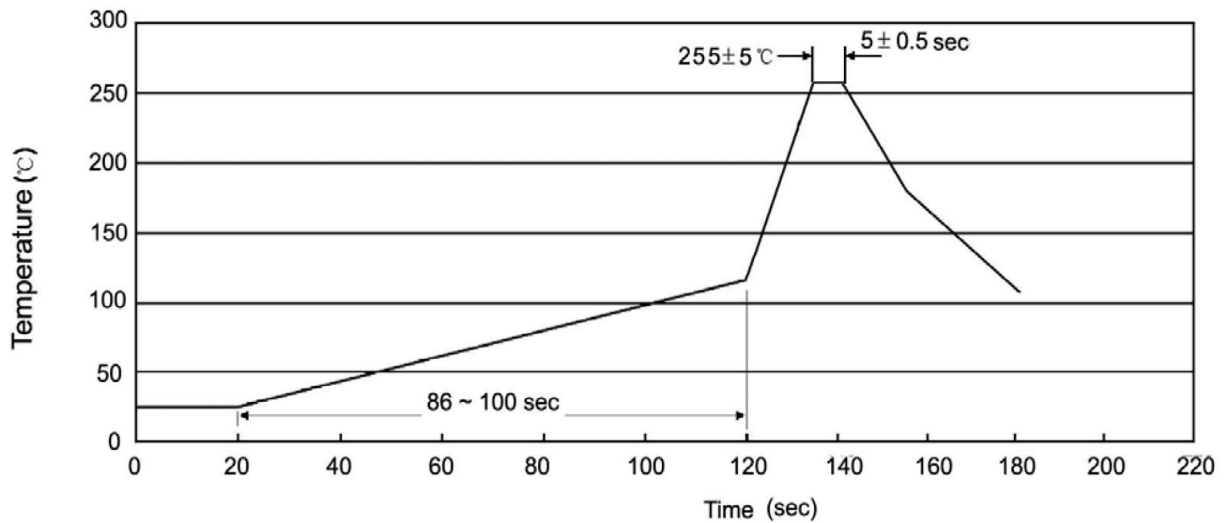
BR: Company Code

BTB20: Product Type.

60B: V_{RRM}/I_{GT} Bracket code

****: Lot No. Code, code change with Lot No.

波峰焊温度曲线图(无铅) / Temperature Profile for Dip Soldering(Pb-Free)



说明：

- 1、预热温度 25 ~ 150°C，时间 60 ~ 90sec；
- 2、峰值温度 255±5°C，时间持续为 5±0.5sec；
- 3、焊接制程冷却速度为 2 ~ 10°C/sec.

Note:

- 1.Preheating:25~150°C, Time:60~90sec.
- 2.Peak Temp.:255±5°C, Duration:5±0.5sec.
3. Cooling Speed: 2~10°C/sec.

耐焊接热试验条件 / Resistance to Soldering Heat Test Conditions

温度：270±5°C

时间：10±1 sec.

Temp.:270±5°C

Time:10±1 sec

包装规格 / Packaging SPEC.

散件包装 / BULK

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Bag 只/袋	Bags/Inner Box 袋/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Bag 袋	Inner Box 盒	Outer Box 箱
TO-220/F	200	10	2,000	5	10,000	135×190	237×172×102	560×245×195

套管包装 / TUBE

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Tube 只/套管	Tubes/Inner Box 套管/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Tube 套管	Inner Box 盒	Outer Box 箱
TO-220/F	50	20	1,000	5	5,000	532×31.4×5.5	555×164×50	575×290×180

使用说明 / Notices